

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- High Power Drives
- High Voltage Power Supplies
- Static Switches

VOLTAGE RATINGS

| Part and Ordering Number | Repetitive Peak Voltages V_{DRM} and V_{RRM} V | Conditions |
|--------------------------|---|---|
| DCR470E34 | 3400 | $T_{vj} = -40\text{ }^{\circ}\text{C to } 125\text{ }^{\circ}\text{C}$, $I_{DRM} = I_{RRM} = 30\text{mA}$, $V_{DRM}, V_{RRM} t_p = 10\text{ms}$, $V_{DSM} \text{ \& } V_{RSM} =$ $V_{DRM} \text{ \& } V_{RRM} + 100\text{V}$ respectively |
| DCR470E32 | 3200 | |
| DCR470E30 | 3000 | |
| DCR470E28 | 2800 | |
| DCR470E26 | 2600 | |
| DCR470E24 | 2400 | |

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DCR470E34

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

KEY PARAMETERS

| | |
|-------------|-----------------------|
| V_{DRM} | 3400 V |
| $I_{T(AV)}$ | 470 A |
| I_{TSM} | 6300 A |
| dV/dt^* | 1000 V/ μs |
| dI/dt | 150 A/ μs |

* Higher dV/dt selections available

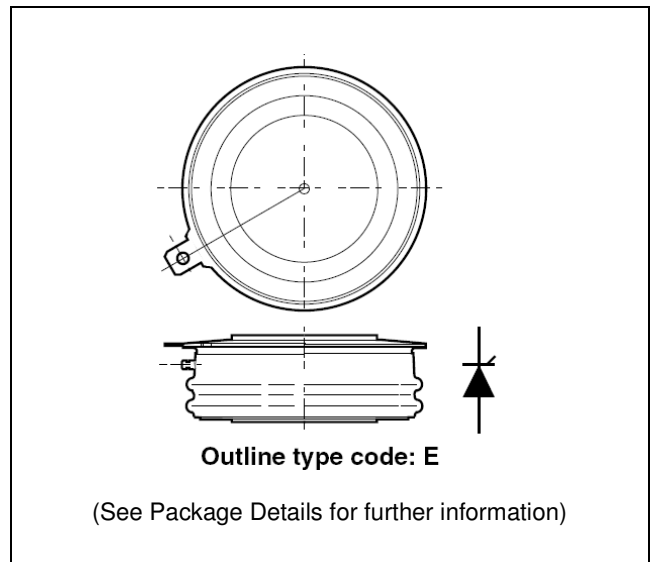


Fig. 1 Package outline

CURRENT RATINGS

T_{case} = 60°C unless stated otherwise

| Symbol | Parameter | Test Conditions | Max. | Units |
|---------------------------|--------------------------------------|--------------------------|------|-------|
| Double Side Cooled | | | | |
| I _{T(AV)} | Mean on-state current | Half wave resistive load | 470 | A |
| I _{T(RMS)} | RMS value | - | 740 | A |
| I _T | Continuous (direct) on-state current | - | 660 | A |

SURGE RATINGS

| Symbol | Parameter | Test Conditions | Max. | Units |
|------------------|---|---|-------|-------------------|
| I _{TSM} | Surge (non-repetitive) on-state current | 10ms half sine, T _{case} = 125°C | 6.3 | kA |
| I ² t | I ² t for fusing | V _R = 0 | 0.198 | MA ² s |

THERMAL AND MECHANICAL RATINGS

| Symbol | Parameter | Test Conditions | Min. | Max. | Units |
|----------------------|---------------------------------------|--|------|-------|-------|
| R _{th(j-c)} | Thermal resistance – junction to case | Double side cooled | - | 0.041 | °C/W |
| R _{th(c-h)} | Thermal resistance – case to heatsink | Double side cooled | - | 0.01 | °C/W |
| T _{vj} | Virtual junction temperature | Blocking V _{DRM} / V _{RRM} | - | 125 | °C |
| T _{stg} | Storage temperature range | | -40 | 140 | °C |
| F _m | Clamping force | | 4 | 6 | kN |

DYNAMIC CHARACTERISTICS

| Symbol | Parameter | Test Conditions | Min. | Max. | Units | |
|-------------------|---|--|-----------------|-------|------------|------------|
| I_{RRM}/I_{DRM} | Peak reverse and off-state current | At V_{RRM}/V_{DRM} , $T_{case} = 125^{\circ}C$ | - | 30 | mA | |
| dV/dt | Max. linear rate of rise of off-state voltage | To 67% V_{DRM} , $T_j = 125^{\circ}C$, gate open | 1000 | - | V/ μs | |
| dl/dt | Rate of rise of on-state current | From 67% V_{DRM} to 1000A Gate source 30V, 10 Ω , $t_r < 0.5\mu s$, $T_j = 125^{\circ}C$ | Repetitive 50Hz | - | 150 | A/ μs |
| | | | Non-repetitive | - | 1000 | A/ μs |
| V_T | On-state voltage | $I_T = 1500A$, $T_{case} = 125^{\circ}C$ | | 3.63 | V | |
| $V_{T(TO)}$ | Threshold voltage | $T_{case} = 125^{\circ}C$ | - | 1.04 | V | |
| r_T | On-state slope resistance | $T_{case} = 125^{\circ}C$ | - | 1.725 | m Ω | |
| t_{gd} | Delay time | $V_D = 67\% V_{DRM}$, gate source 30V, 10 Ω $t_r = 0.5\mu s$, $T_j = 25^{\circ}C$ | - | 3.0 | μs | |
| I_L | Latching current | $T_j = 25^{\circ}C$, | - | 1 | A | |
| I_H | Holding current | $T_j = 25^{\circ}C$, | - | 200 | mA | |

GATE TRIGGER CHARACTERISTICS AND RATINGS

| Symbol | Parameter | Test Conditions | Max. | Units |
|----------|--------------------------|--|------|-------|
| V_{GT} | Gate trigger voltage | $V_{DRM} = 5V$, $T_{case} = 25^{\circ}C$ | 3 | V |
| V_{GD} | Gate non-trigger voltage | At 40% V_{DRM} , $T_{case} = 125^{\circ}C$ | TBD | V |
| I_{GT} | Gate trigger current | $V_{DRM} = 5V$, $T_{case} = 25^{\circ}C$ | 300 | mA |
| I_{GD} | Gate non-trigger current | At 40% V_{DRM} , $T_{case} = 125^{\circ}C$ | TBD | mA |

CURVES

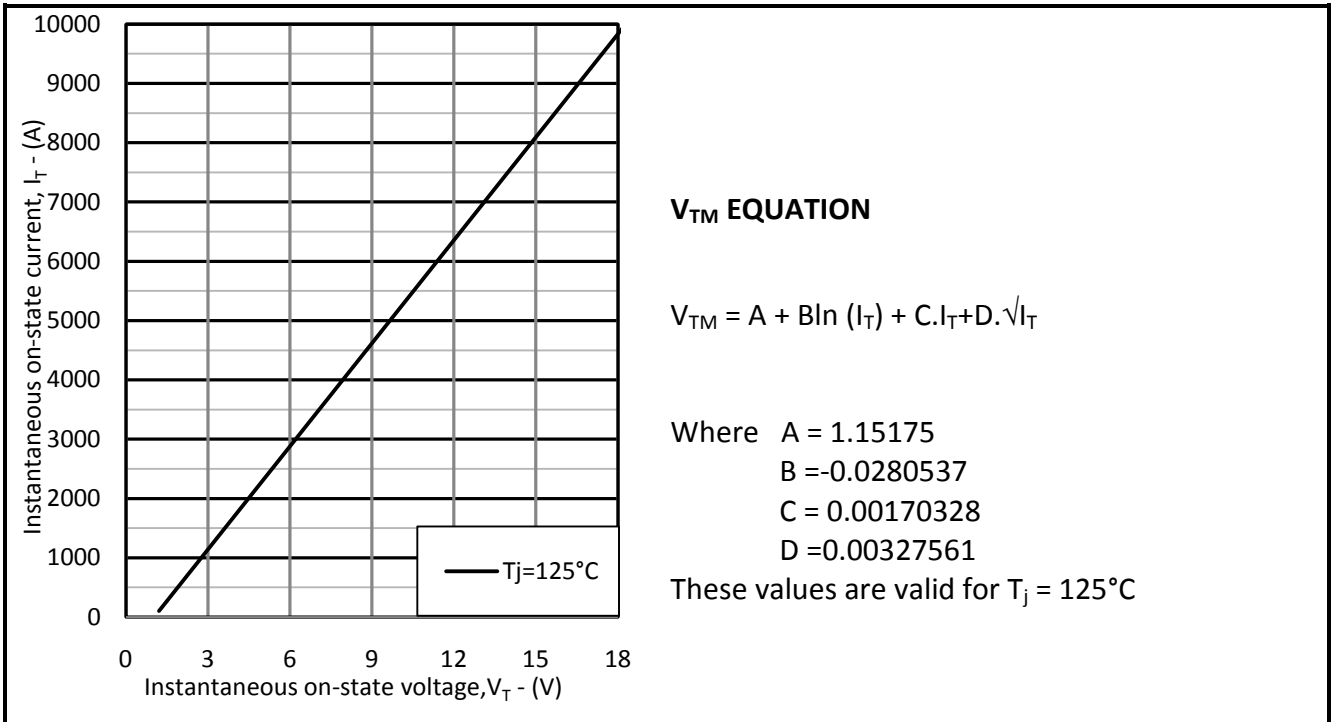


Fig.2 Maximum & minimum on-state characteristics

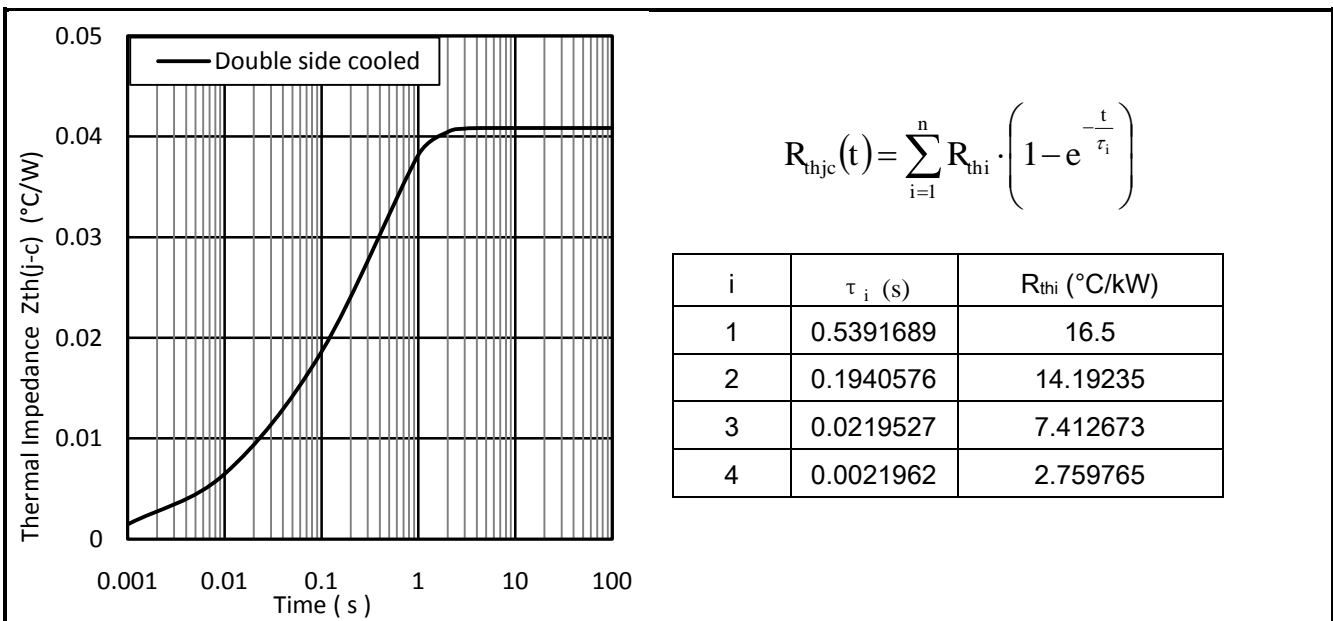


Fig.3 Maximum (limit) transient thermal impedance – junction to case (°C/W)

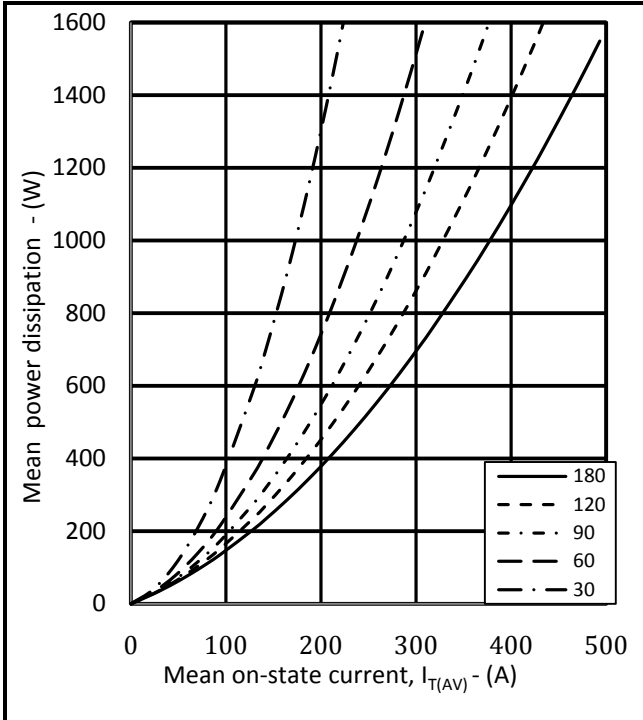


Fig.4 On-state power dissipation – sine wave

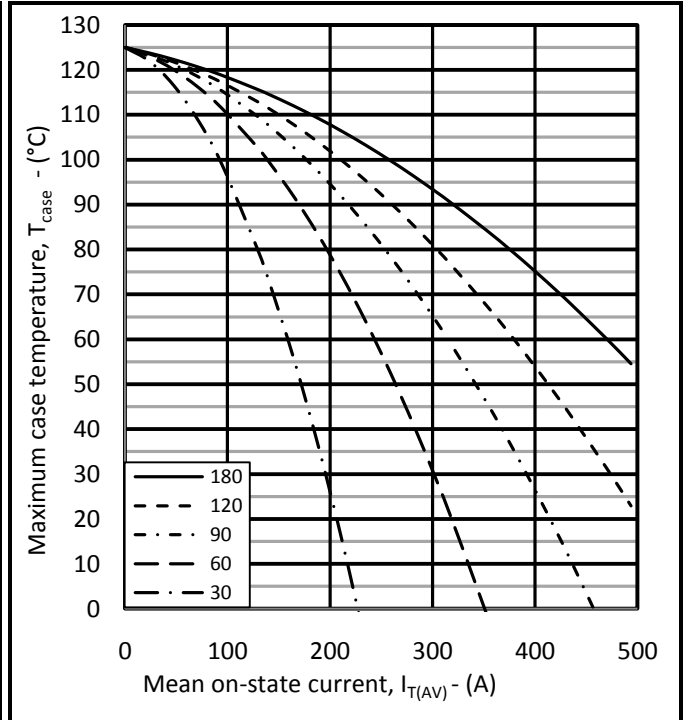


Fig.5 Maximum permissible case temperature, double side cooled – sine wave

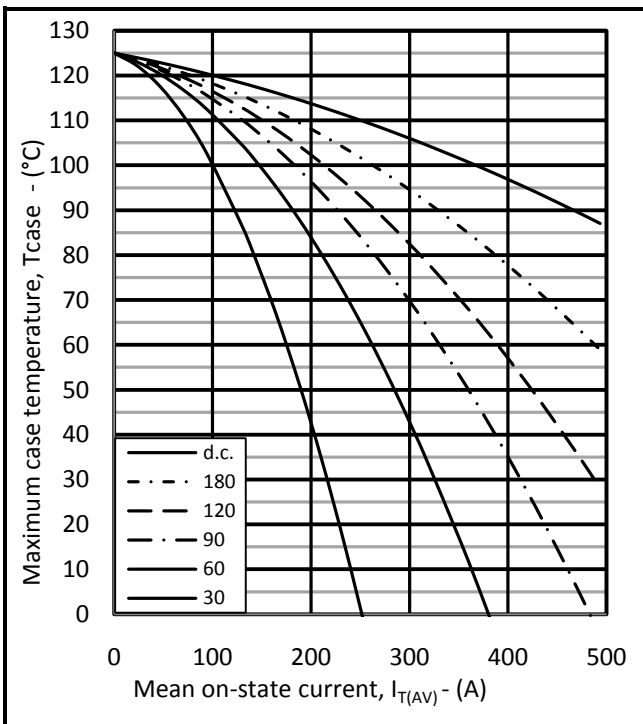


Fig.6 Maximum permissible case temperature, double side cooled – rectangular wave

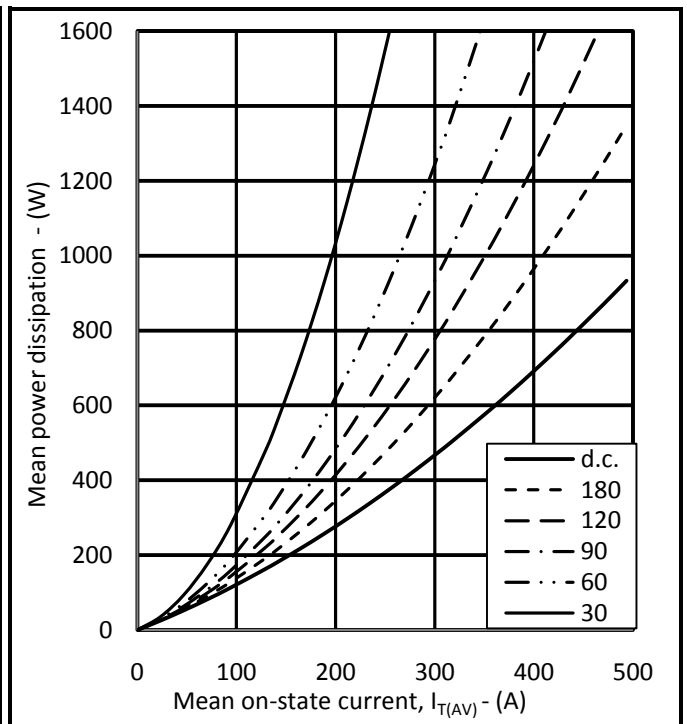


Fig.7 On-state power dissipation – rectangular wave

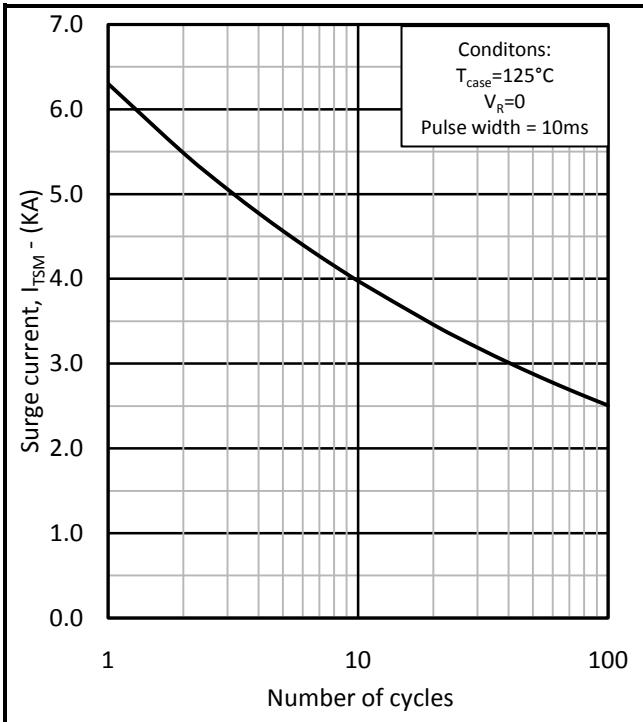


Fig.8 Multi-cycle surge current

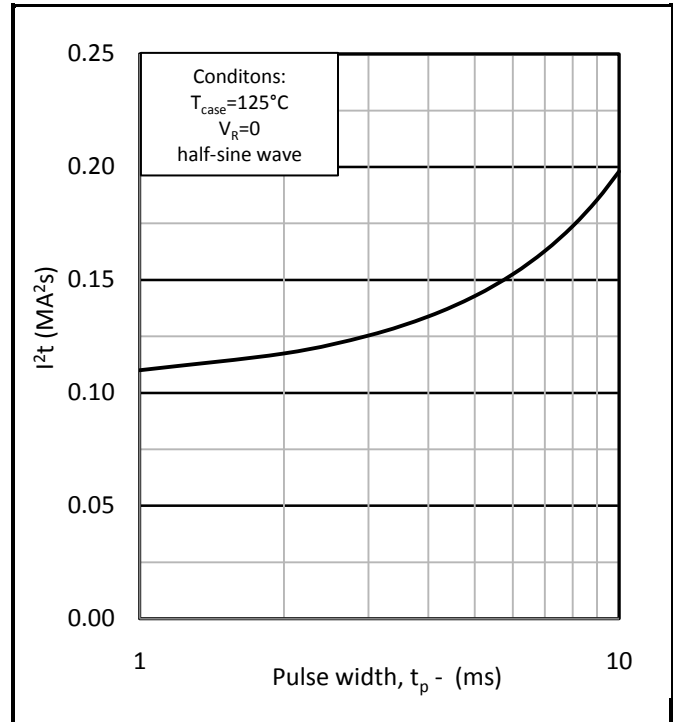


Fig.9 Single-cycle I^2t

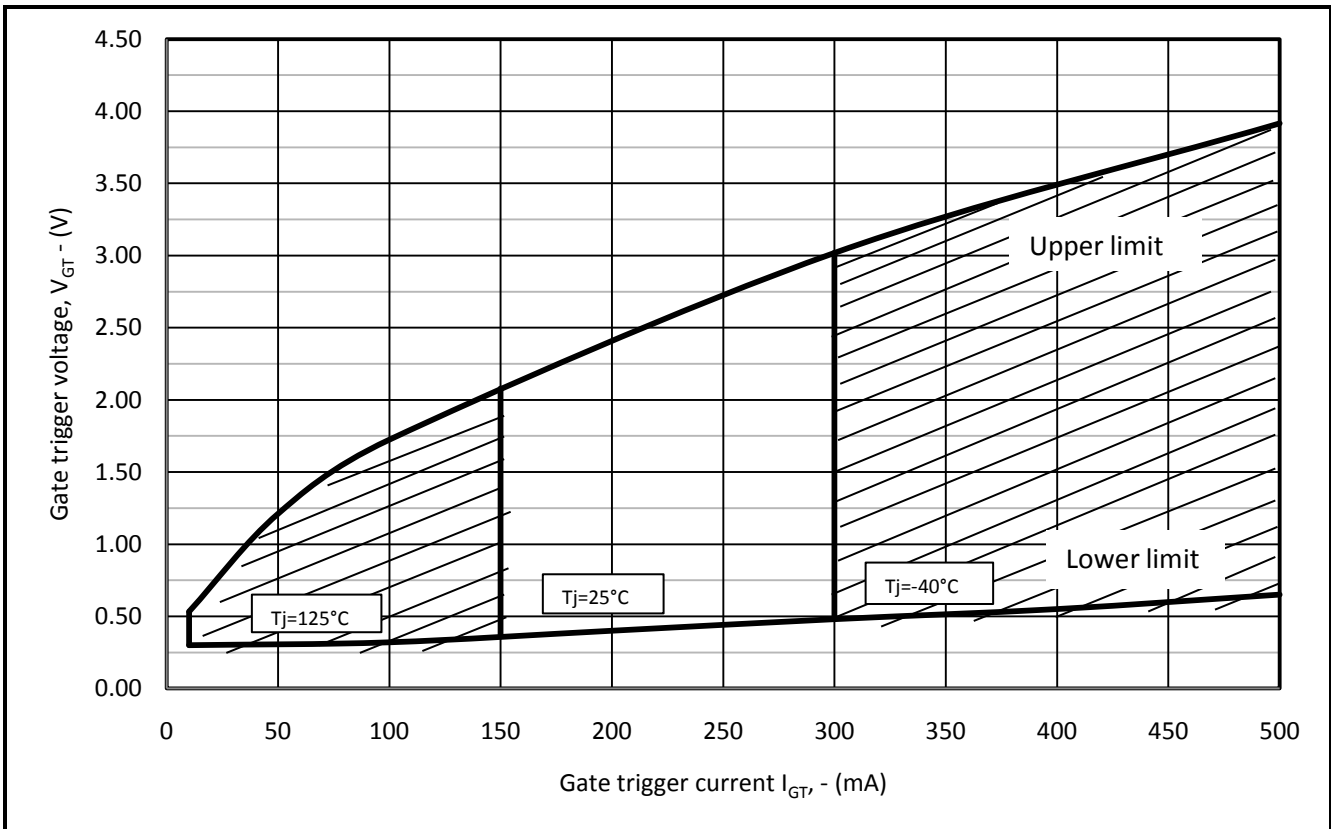


Fig.10 Gate characteristics

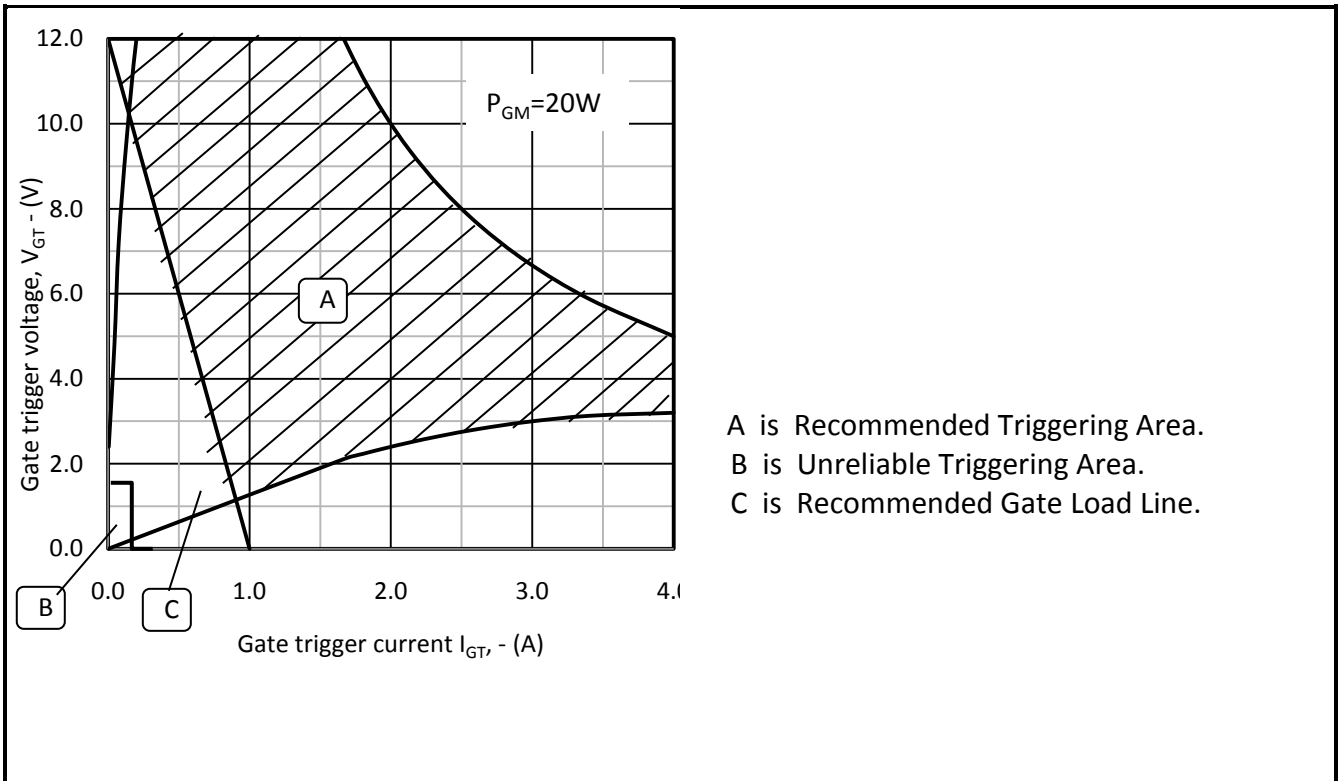


Fig.11 Gate characteristics

PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

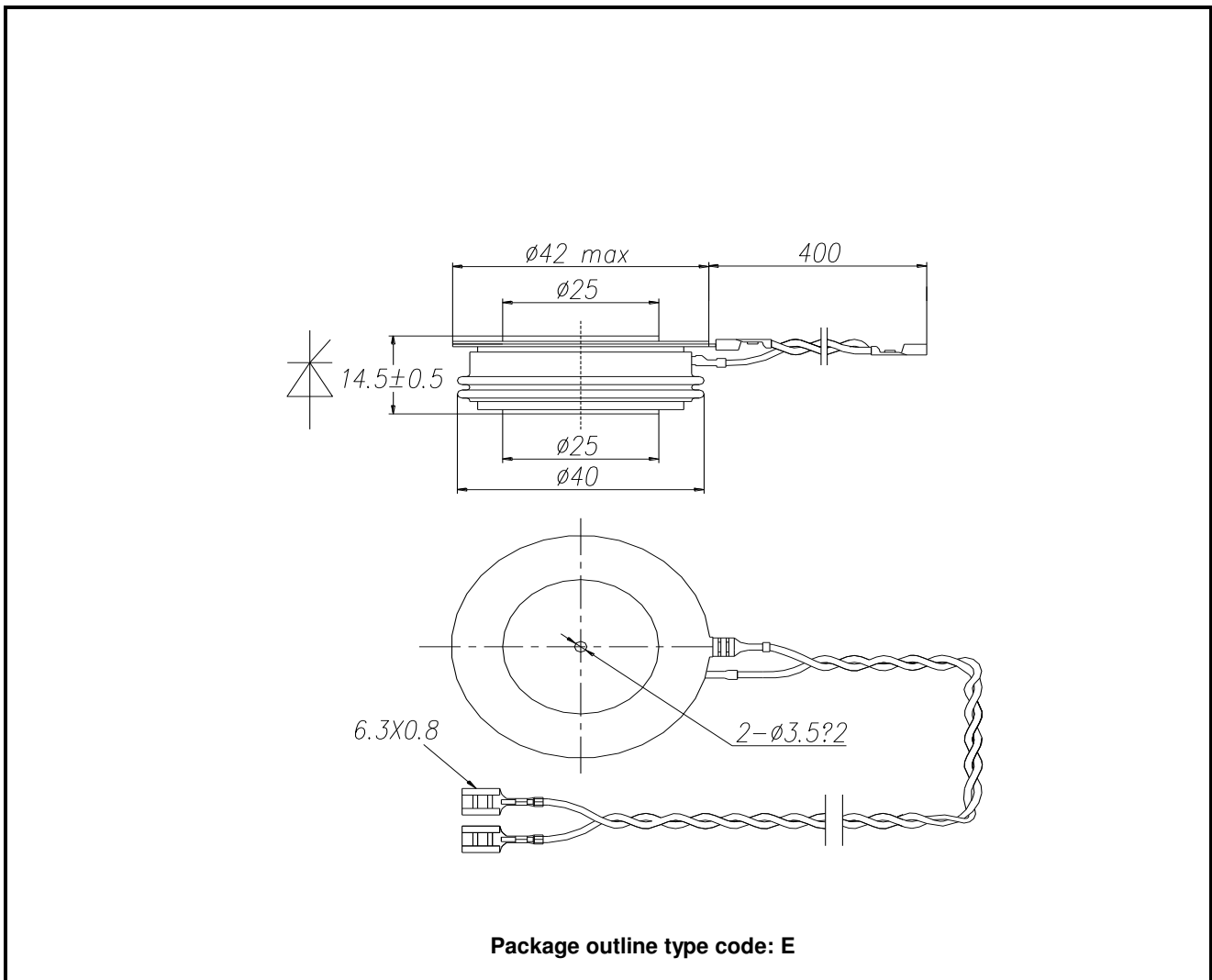


Fig.12 Package outline

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| | |
|---------------------------------|---|
| Target Information: | This is the most tentative form of information and represents a very preliminary specification. No actual design work on the product has been started. |
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HEADQUARTERS OPERATIONS

DYNEX SEMICONDUCTOR LIMITED
Doddington Road, Lincoln, Lincolnshire, LN6 3LF
United Kingdom.
Phone: +44 (0) 1522 500500
Fax: +44 (0) 1522 500550
Web: <http://www.dynexsemi.com>

CUSTOMER SERVICE

Phone: +44 (0) 1522 502753 / 502901
Fax: +44 (0) 1522 500020
e-mail: power_solutions@dynexsemi.com